



# PFR<sup>®</sup>-800 AUS<sup>®</sup> SR1 (Trial #64329)

## FC 用現像型ソルダーレジストドライフィルム

### Dry Film Solder Resist for Flip Chip Substrate Application

● **投影露光 / 直描露光対応**

Product line up suitable to various exposure units (Projection, Direct Imaging)

● **高 Tg/ 低 CTE 材 : 優れた TCT/PCT 耐性**

Tough resin structure with High Tg/Low CTE for TCT and PCT resistance

● **高精細での優れた電気特性**

Electrical reliability: No migration failure with L/S 15/10 $\mu$ m after 200hrs, 12V, 130 $^{\circ}$ C/85%Rh

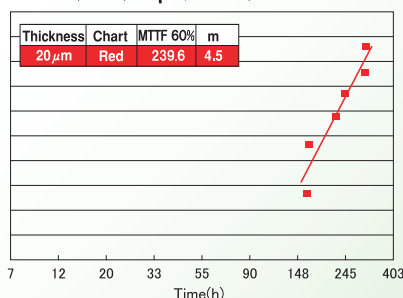
### 仕様 Specification

膜厚 Resin thickness	20 $\mu$ m (standard) – Adjustable
色調 Color	Green
保管条件 Storage condition	Below –15 $^{\circ}$ C
推奨硬化条件 Recommended curing condition	160 $^{\circ}$ C, 60min.

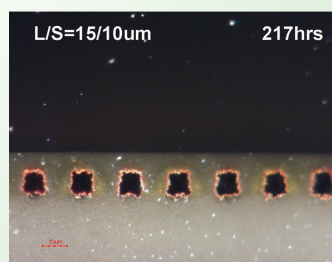
### 特性 Properties

ガラス転移点 Tg *TMA method	130 – 140 $^{\circ}$ C
線膨張係数 CTE	$\alpha 1$ 40 – 45 ppm
弾性率 Young's modulus	3.5 – 4.0 GPa
破壊強度 Tensile strength	70 – 75 MPa
破壊伸び率 Elongation	3.5 – 4.0 %
感度 Photosensitivity	350 mJ/cm <sup>2</sup>
解像性 SRO resolution	50 $\mu$ m in diameter
PCT 耐性 (121 $^{\circ}$ C, 2.1atm, 100%Rh, 200hrs)	No peeling
HAST 耐性 (130 $^{\circ}$ C, 85%Rh, 12V, 168hrs, L/S=15/10 $\mu$ m)	No migration
TCT 耐性 (-65 $\leftrightarrow$ 150 $^{\circ}$ C, 1000cycles)	Pass

Weibull plot in BHAST  
L/S15/10 $\mu$ m, 130 $^{\circ}$ C/85% 12V



After 217hrs HAST 130 $^{\circ}$ C/85% 12V



SRO 50 $\mu$ m by USIO Projector 350 mJ/cm<sup>2</sup>

